NSN 5962-01-135-2103

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View Online at https://aerobasegroup.com/nsn/5962-01-135-2103

| Body Length: |
|--|
| 1.310 inches |
| Body Width: |
| 0.600 inches |
| Body Height: |
| 0.052 inches |
| Maximum Power Dissipation Rating: |
| 400.0 milliwatts |
| Operating Tempurature Range: |
| +0.0/+75.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| Training dev 08783 |
| Features Provided: |
| Hermetically sealed and programmable and expandable and wire-or outputs and w/enable |
| Inclosure Material: |
| Ceramic and glass |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 8 input |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -1.5 volts power source and 5.5 volts power source |
| Time Rating Per Chacteristic: |
| 75.00 nanoseconds propagation delay time, low to high level output |
| Memory Device Type: |
| Rom |
| Memory Capacity: |
| Unknown |
| Terminal Type And Quantity: |
| 24 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |

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